Infrared light emitting diode, top view type SIR-34ST3F

The SIR-34ST3F is a GaAs infrared light emitting diode housed in clear plastic. This device has a high luminous efficiency and a 950 nm spectrum suitable for silicon detectors. It is small and at the same time has a wide radiation angle, making it ideal for compact optical control equipment.

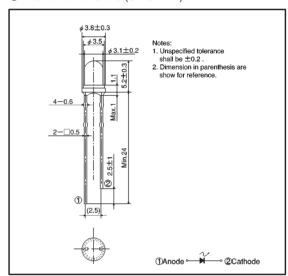
Applications

Optical control equipment Light source for remote control devices

Features

- 1) Compact (φ3.1 mm).
- 2) High efficiency, high output Po = 8.0 mW (I_F = 50 mA).
- 3) Wide radiation angle $\theta = 27^{\circ}$.
- 4) Emission spectrum well suited to silicon detectors $(\lambda_P = 950 \text{ nm}).$
- 5) Good current-optical output linearity.
- 6) Long life, high reliability.
- 7) Low cost, clear epoxy resin package.

External dimensions (Units: mm)



● Absolute maximum ratings (Ta = 25°C)

| Parameter | Symbol | Limits | Unit |
|-----------------------|--------|----------------|------|
| Forward current | lF | 100 | mA |
| Reverse voltage | VR | 5 | V |
| Power dissipationt | ₽p | 160 | mW |
| Pulse forward current | IFP* | 1.0 | Α |
| Operating temperature | Topr | -25~+85 | °C |
| Storage temperature | Tstg | −40~+85 | °C |

^{*} Pulse width = 0.1 msec, duty ratio 1%

Sensors SIR-34ST3F

●Electrical and optical characteristics (Ta = 25°C)

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions |
|--------------------------------|---------|------|------|------|-------|--------------------|
| Optical output | Po | _ | 8.0 | _ | mW | I==50mA |
| Emitting strength | lε | 3.5 | _ | 28.0 | mW/sr | I==50mA |
| Forward voltage | VF | _ | 1.3 | 1.6 | V | I==100mA |
| Reverse current | lR | _ | _ | 10 | μΑ | V _R =3V |
| Peak light emitting wavelength | λр | _ | 950 | _ | nm | I==50mA |
| Spectral line half width | Δλ | _ | 40 | _ | nm | I==50mA |
| Harf-viewing angle | θ 1/2 | _ | ±27 | _ | deg | I==50mA |
| Response time | tr • tf | _ | 1.0 | _ | μS | I==50mA |
| Cut-off frequency | fc | _ | 1.0 | _ | MHz | I==50mA |

Electrical and optical pattern curves

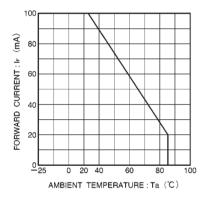


Fig.1 Forward current falloff

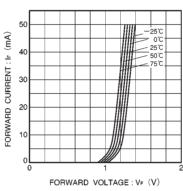


Fig. 2 Forward current vs. forward voltage

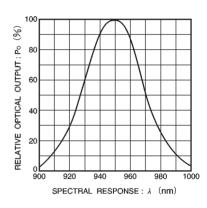


Fig. 3 Wavelength

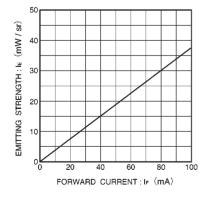


Fig.4 Emitting strength vs. forward current

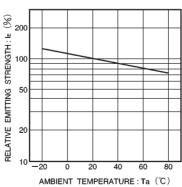


Fig.5 Relative emitting strength vs. ambient temperature

Sensors SIR-34ST3F

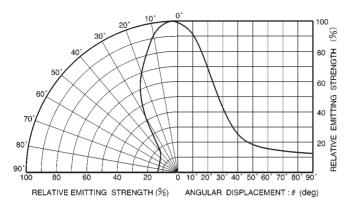


Fig.6 Directional pattern